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APPLICATIONS:

- Drivers
- Switches
- Medium-Power Amplifiers

FEATURES:

- Low Saturation Voltage: 0.6 V_{CE(sat)} @ I_C = 1.0 Amp
- High Gain Characteristics: hFE @ I_C = 250 mA: 30-100
- Excellent Safe Area Limits
- Low Collector Cutoff Current: 100 nA (Max) 2N3741A

DESCRIPTION:

These power transistors are produced by PPC's DOUBLE DIFFUSED PLANAR process. This technology produces high voltage devices with excellent switching speeds, frequency response, gain linearity, saturation voltages, high current gain, and safe operating areas. They are intended for use in Commercial, Industrial, and Military power switching, amplifier, and regulator applications.

Ultrasonically bonded leads and controlled die mount techniques are utilized to further increase the SOA capability and inherent reliability of these devices. The temperature range to 200°C permits reliable operation in high ambients, and the hermetically sealed package insures maximum reliability and long life.

ABSOLUTE MAXIMUM RATINGS:

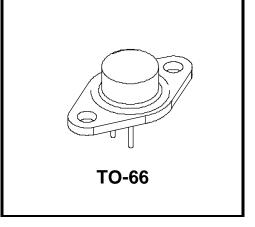
| SYMBOL | CHARACTERISTIC | VALUE | UNITS | |
|--------------------|--------------------------------|------------|-------|--|
| V _{CEO} * | Collector-Emitter Voltage | 80 | Vdc | |
| V _{EB} * | Emitter-Base Voltage | 7.0 | Vdc | |
| V _{CB} * | Collector-Base Voltage | 80 | Vdc | |
| lc* | Peak Collector Current | 10 | Adc | |
| lc* | Continuous Collector Current | 4.0 | Adc | |
| IB* | Base Current | 2.0 | Adc | |
| T _{STG} * | Storage Temperature | -65 to 200 | °C | |
| TJ* | Operating Junction Temperature | -65 to 200 | °C | |
| P _D * | Total Device Dissipation | 25 | Watts | |
| - | T _C = 25°C | | | |
| | Derate above 25°C | 0.143 | W/∘C | |
| θJC | Thermal Impedance | 7 | °C/W | |

* Indicates JEDEC registered data.

PNP Transistors

2N3741A

Medium Power





ELECTRICAL CHARACTERISTICS: (25°Case Temperature Unless Otherwise Noted)

Microsemi

Progress Powered by Technology

| SYMBOL | CHARACTERISTIC | | VAL | VALUE | |
|------------------------|---|---|-----|-------|-------|
| | | TEST CONDITIONS | | Max. | Units |
| V _{CEO(sus)*} | Collector-Emitter Sustaining Voltage | I _C = 100 mAdc, I _B = 0 (Note 1) | 80 | | Vdc |
| I _{EB0*} | Emitter Base Cutoff Current | V _{EB} = 7.0 Vdc | | 100 | nAdc |
| I _{CEX*} | Collector Cutoff Current | V _{CE} = 80 Vdc, V _{BE(off)} = 1.5 Vdc | | 100 | nAdc |
| | | $V_{CE} = 60 \text{ Vdc}, V_{BE(off)} = 1.5 \text{ Vdc}, T_{C} = 150^{\circ}\text{C}$ | | 0.5 | mAdc |
| I _{CEO} * | Collector-Emitter Cutoff Current | $V_{CE} = 60 \text{ Vdc}, \ I_B = 0$ | | 1.0 | μAdc |
| Ісво* | Collector Base Cutoff Current | $V_{CB} = 80 \text{ Vdc}, \ I_E = 0$ | | 100 | nAdc |
| h _{FE} * | DC Current Gain (Note 1) | $I_{C} = 100 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$ | 40 | | |
| | | $I_C = 250 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$ | 30 | 100 | |
| | | $I_C = 500 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$ | 20 | | |
| | | $I_{C} = 1.0 \text{ Adc}, V_{CE} = 1.0 \text{ Vdc}$ | 10 | | |
| V _{CE(sat)} * | Collector-Emitter Saturation Voltage (Note 1) | $I_{\rm C}$ = 1.0 Adc, $I_{\rm B}$ = 125 mAdc | | 0.6 | Vdc |
| V _{BE*} | Base-Emitter Voltage (Note 1) | $I_{C} = 250 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$ | | 1.0 | Vdc |
| f _T * | Current Gain Bandwidth Product | $I_{C} = 100 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ MHz}$ | 3.0 | | MHz |
| h _{fe} * | Small-Signal Current Gain | $I_{C} = 50 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz}$ | 25 | | |
| C _{ob*} | Common Base Output Capacitance | $V_{CB} = 10 \text{ Vdc}, \ I_C = 0, \ f = 100 \text{ kHz}$ | | 100 | pF |

Note 1: Pulse Test: PW \leq 300 μ s, Duty Cycle \leq 2.0%

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PACKAGE MECHANICAL DATA:

